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# N01L083WC2A

## 1Mb Ultra-Low Power Asynchronous CMOS SRAM 128Kx8 bit

## Overview

The N01L083WC2A is an integrated memory device containing a 1 Mbit Static Random Access Memory organized as 131,072 words by 8 bits. The device is designed and fabricated using NanoAmp's advanced CMOS technology to provide both high-speed performance and ultra-low power. The base design is the same as NanoAmp's N01L1618N1A, which is processed to operate at lower voltages. The device operates with two chip enable (CE1 and CE2) controls and output enable ( $\overline{OE}$ ) to allow for easy memory expansion. The N01L083WC2A is optimal for various applications where low-power is critical such as battery backup and hand-held devices. The device can operate over a very wide

temperature range of -40°C to +85°C and is available in JEDEC standard packages compatible with other standard 128Kb x 8 SRAMs

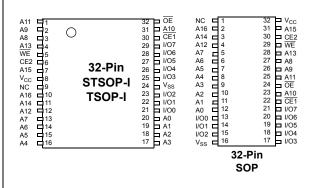
## Features

- Single Wide Power Supply Range 2.3 to 3.6 Volts
- Very low standby current 2.0µA at 3.0V (Typical)
- Very low operating current 2.0mA at 3.0V and 1µs (Typical)
- Very low Page Mode operating current 0.8mA at 3.0V and 1µs (Typical)
- Simple memory control Dual Chip Enables (CE1and CE2) Output Enable (OE) for memory expansion
- Low voltage data retention Vcc = 1.8V
- Very fast output enable access time 30ns OE access time
- Automatic power down to standby mode
- TTL compatible three-state output driver

Part Number	Package Type	Operating Temperature	Power Supply (Vcc)	Speed	Standby Current (I <sub>SB</sub> ), Typical	Operating Current (Icc), Typical
N01L083WC2AT	32 - TSOP I					
N01L083WC2AN	32 - STSOP I	-40°C to +85°C	2.3V - 3.6V	55ns @ 2.7V 70ns @ 2.3V	2 μΑ	2 mA @ 1MHz
N01L083WC2AS	32 SOP			<u> </u>		

#### **Pin Configuration**

**Product Family** 

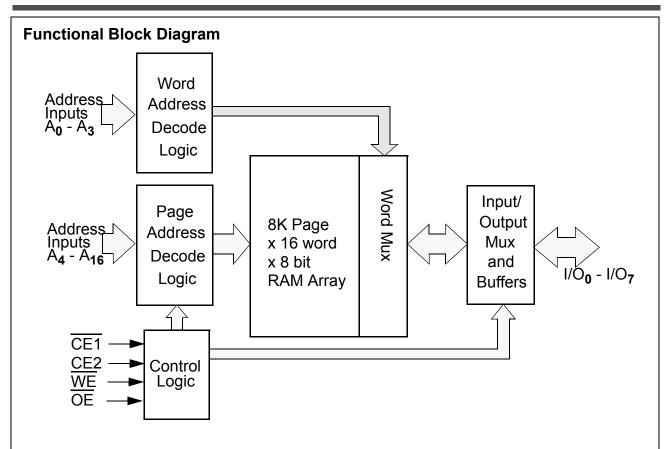


#### **Pin Descriptions**

Pin Name	Pin Function		
A <sub>0</sub> -A <sub>16</sub>	Address Inputs		
WE	Write Enable Input		
CE1, CE2	Chip Enable Input		
OE	Output Enable Input		
1/0 <sub>0</sub> -1/0 <sub>7</sub>	Data Inputs/Outputs		
V <sub>CC</sub>	Power		
V <sub>SS</sub>	Ground		
NC	Not Connected		

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## **Functional Description**

CE1	CE2	WE	OE	I/O <sub>0</sub> - I/O <sub>7</sub>	MODE	POWER
Н	х	Х	Х	High Z	Standby <sup>1</sup>	Standby
Х	L	Х	Х	High Z	Standby <sup>1</sup>	Standby
L	Н	L	X <sup>2</sup>	Data In	Write <sup>2</sup>	Active
L	Н	Н	L	Data Out	Read	Active
L	Н	Н	Н	High Z	Active	Active

1. When the device is in standby mode, control inputs ( $\overline{WE}$  and  $\overline{OE}$ ), address inputs and data input/outputs are internally isolated from any external influence and disabled from exerting any influence externally.

2. When  $\overline{\text{WE}}$  is invoked, the  $\overline{\text{OE}}$  input is internally disabled and has no effect on the circuit.

## Capacitance<sup>1</sup>

ltem	Symbol	Test Condition	Min	Мах	Unit
Input Capacitance	C <sub>IN</sub>	V <sub>IN</sub> = 0V, f = 1 MHz, T <sub>A</sub> = 25 <sup>o</sup> C		8	pF
I/O Capacitance	C <sub>I/O</sub>	V <sub>IN</sub> = 0V, f = 1 MHz, T <sub>A</sub> = 25 <sup>o</sup> C		8	pF

1. These parameters are verified in device characterization and are not 100% tested

#### Absolute Maximum Ratings<sup>1</sup>

Item	Symbol	Rating	Unit
Voltage on any pin relative to $V_{SS}$	V <sub>IN,OUT</sub>	–0.3 to V <sub>CC</sub> +0.3	V
Voltage on $V_{CC}$ Supply Relative to $V_{SS}$	V <sub>CC</sub>	–0.3 to 4.5	V
Power Dissipation	PD	500	mW
Storage Temperature	T <sub>STG</sub>	-40 to 125	°C
Operating Temperature	T <sub>A</sub>	-40 to +85	°C
Soldering Temperature and Time	T <sub>SOLDER</sub>	240°C, 10sec(Lead only)	°C

1. Stresses greater than those listed above may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operating section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

#### **Operating Characteristics (Over Specified Temperature Range)**

Item	Symbol	Test Conditions	Min.	Typ <sup>1</sup>	Max	Unit
Supply Voltage	V <sub>CC</sub>		2.3	3.0	3.6	V
Data Retention Voltage	$V_{DR}$	Chip Disabled <sup>3</sup>	1.8			V
Input High Voltage	V <sub>IH</sub>		1.8		V <sub>CC</sub> +0.3	V
Input Low Voltage	V <sub>IL</sub>		-0.3		0.6	V
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = 0.2mA	V <sub>CC</sub> -0.2			V
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = -0.2mA			0.2	V
Input Leakage Current	Ι <sub>LI</sub>	$V_{IN}$ = 0 to $V_{CC}$			0.5	μA
Output Leakage Current	I <sub>LO</sub>	$\overline{OE} = V_{IH}$ or Chip Disabled			0.5	μA
Read/Write Operating Supply Current @ 1 µS Cycle Time <sup>2</sup>	I <sub>CC1</sub>	V <sub>CC</sub> =3.6 V, V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub> Chip Enabled, I <sub>OUT</sub> = 0		2.0	3.0	mA
Read/Write Operating Supply Current @ 70 nS Cycle Time <sup>2</sup>	I <sub>CC2</sub>	V <sub>CC</sub> =3.6 V, V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub> Chip Enabled, I <sub>OUT</sub> = 0		9.5	14.0	mA
Page Mode Operating Supply Current @ 70ns Cycle Time <sup>2</sup> (Refer to Power Savings with Page Mode Operation diagram)	I <sub>CC3</sub>	V <sub>CC</sub> =3.6 V, V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub> Chip Enabled, I <sub>OUT</sub> = 0,		4		mA
Read/Write Quiescent Operating Sup- ply Current <sup>3</sup>	I <sub>CC4</sub>	$V_{CC}$ =3.6 V, $V_{IN}$ = $V_{IH}$ or $V_{IL}$ Chip Enabled, $I_{OUT}$ = 0, f = 0			3.0	mA
Maximum Standby Current <sup>3</sup>	I <sub>SB1</sub>	$V_{IN} = V_{CC} \text{ or } 0V$ Chip Disabled $t_A = 85^{\circ}C, V_{CC} = 3.6 V$		2.0	20	μA
Maximum Data Retention Current <sup>3</sup>	I <sub>DR</sub>	Vcc = 1.8V, $V_{IN} = V_{CC}$ or 0 Chip Disabled, $t_A = 85^{\circ}C$			10	μA

1. Typical values are measured at Vcc=Vcc Typ.,  $T_A$ =25°C and not 100% tested.

2. This parameter is specified with the outputs disabled to avoid external loading effects. The user must add current required to drive output capacitance expected in the actual system.

3. This device assumes a standby mode if the chip is disabled ( $\overline{CE1}$  high or CE2 low). In order to achieve low standby current all inputs must be within 0.2 volts of either VCC or VSS.

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Power Savings	s with	Page Mode	Operation	$(WE = V_{I})$	ін)
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Page Ad	ddress (A4 - A16)	
Word Ad	ddress (A0 - A3)	16
CE1		
CE2		
ŌE		

Note: Page mode operation is a method of addressing the SRAM to save operating current. The internal organization of the SRAM is optimized to allow this unique operating mode to be used as a valuable power saving feature.

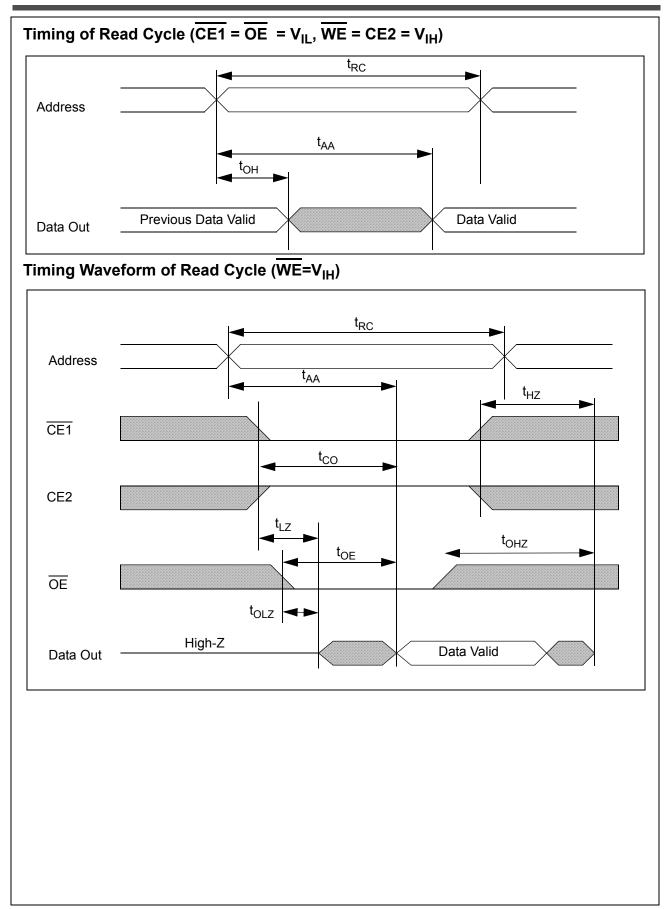
The only thing that needs to be done is to address the SRAM in a manner that the internal page is left open and 8-bit words of data are read from the open page. By treating addresses A0-A3 as the least significant bits and addressing the 16 words within the open page, power is reduced to the page mode value which is considerably lower than standard operating currents for low power SRAMs.

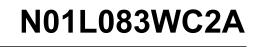
### **Timing Test Conditions**

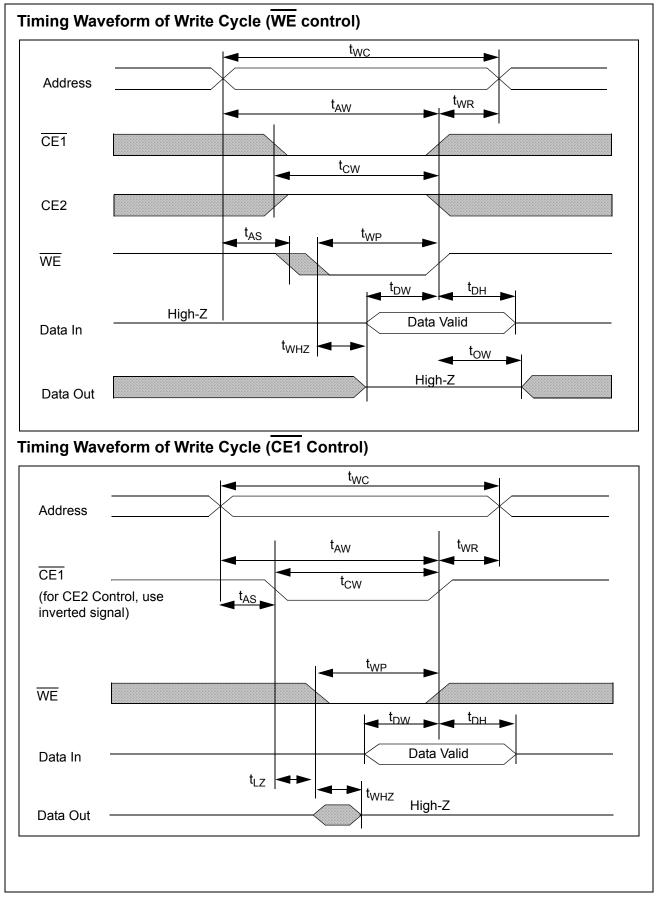
Item	
Input Pulse Level	0.1V <sub>CC</sub> to 0.9 V <sub>CC</sub>
Input Rise and Fall Time	5ns
Input and Output Timing Reference Levels	0.5 V <sub>CC</sub>
Output Load	CL = 30pF
Operating Temperature	-40 to +85 <sup>o</sup> C

#### Timing

Item	Cumhal	2.3 -	3.6 V	2.7 - 3.6 V		Units
ltem	Symbol	Min.	Max.	Min.	Max.	Units
Read Cycle Time	t <sub>RC</sub>	70		55		ns
Address Access Time	t <sub>AA</sub>		70		55	ns
Chip Enable to Valid Output	t <sub>co</sub>		70		55	ns
Output Enable to Valid Output	t <sub>OE</sub>		35		30	ns
Chip Enable to Low-Z output	t <sub>LZ</sub>	10		10		ns
Output Enable to Low-Z Output	t <sub>OLZ</sub>	5		5		ns
Chip Disable to High-Z Output	t <sub>HZ</sub>	0	20	0	15	ns
Output Disable to High-Z Output	t <sub>онz</sub>	0	20	0	15	ns
Output Hold from Address Change	t <sub>он</sub>	10		10		ns
Write Cycle Time	t <sub>WC</sub>	70		55		ns
Chip Enable to End of Write	t <sub>CW</sub>	50		45		ns
Address Valid to End of Write	t <sub>AW</sub>	50		45		ns
Write Pulse Width	t <sub>WP</sub>	40		35		ns
Address Setup Time	t <sub>AS</sub>	0		0		ns
Write Recovery Time	t <sub>WR</sub>	0		0		ns
Write to High-Z Output	t <sub>WHZ</sub>		20		15	ns
Data to Write Time Overlap	t <sub>DW</sub>	40		35		ns
Data Hold from Write Time	t <sub>DH</sub>	0		0		ns
End Write to Low-Z Output	t <sub>OW</sub>	5		5		ns



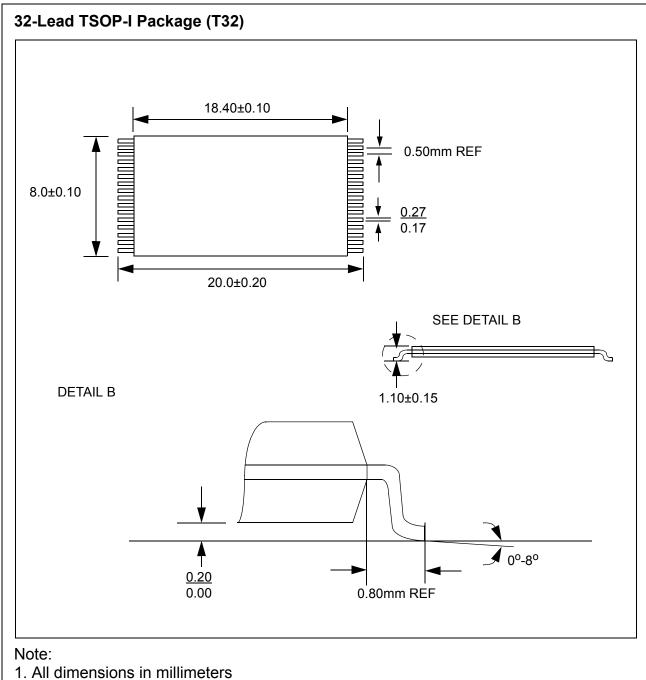




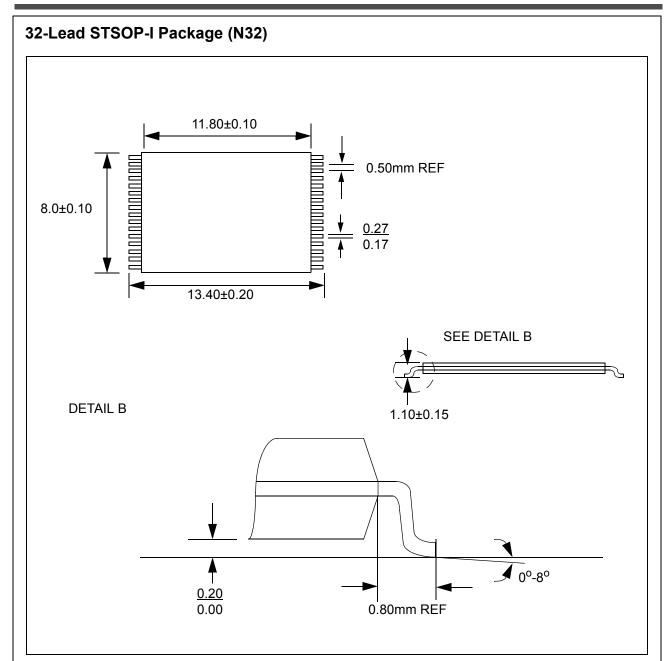
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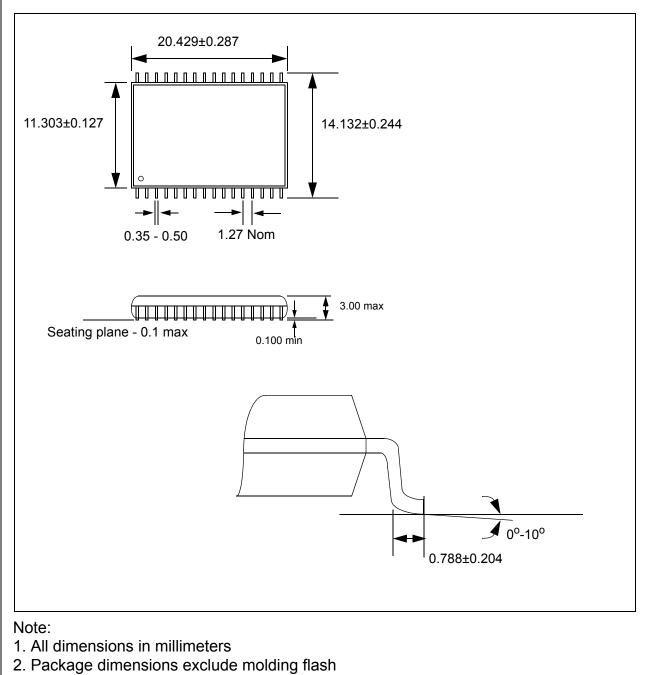
2. Package dimensions exclude molding flash

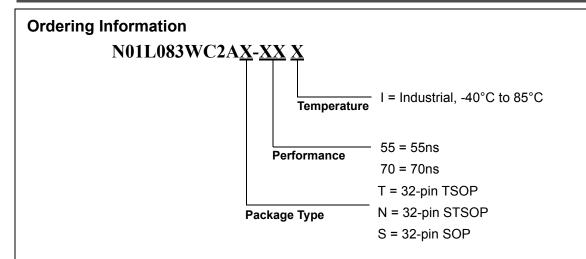


#### Note:

- 1. All dimensions in millimeters
- 2. Package dimensions exclude molding flash

## 32-Lead SOP Package





#### **Revision History**

Revision #	Date	Change Description
01	Jan 2001	Initial Advance Release
02	Mar 2001	Added Table 3: Capacitance Revised quiescent operating current, changed pin 31 to CE1, modified Pin Description and Pin Configuration, other minor edits
03	Dec. 2001	Part number change from EM128L08, modified Overview and Features, added Page Mode Operation diagram and Package diagrams, revised Operating Char- acteristics table, Functional Description table, Timing diagrams, and Ordering Information diagram
04	Nov. 2002	Replaced Isb and Icc on Product Family table with typical values
05	Dec. 2002	Add 32-pin SOP package

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